NSN 5961-01-545-8568

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-545-8568 **Inclosure Material:** Ceramic **Overall Length:** Between 0.780 inches and 0.810 inches **Terminal Length:** Between 0.020 inches and 0.125 inches Overall Width: 0.320 inches **End Application:** Circuit card assembly **Component Name And Quantity:** 1 transistor **Mounting Method: Terminal Terminal Circle Diameter:** Between 0.008 inches and 0.012 inches **Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 20.0 collector to base voltage, dc all transistor **Current Rating Per Characteristic:** 20.00 milliamperes all primaries all transistor **Power Rating Per Characteristic:** 200.0 milliwatts any acceptable preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Product Name:** (inavy)ic high frequency (drawing)ic high frequency, npn transistor array(a3263503) **Special Features:** Operating temperature: -55 to 125 degrees celsius **Terminal Type And Quantity:** 16 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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